

Power Amplifier/Antenna Switch + Low Noise Down Conversion Mixer for PHS

Description

The CXG1051AFN is an MMIC consisting of the power amplifier, antenna switch and low noise down conversion mixer.

This IC is designed using the Sony's GaAs J-FET process featuring a single positive power supply operation.

Features

- Operates at a single positive power supply: $V_{DD} = 3V$
- Small mold package: 26-pin HSOF

<Power amplifier/antenna switch transmitter block>

- Low current consumption: $I_{DD} = 150mA$
($P_{OUT} = 20.2dBm$, $f = 1.9GHz$)
- High power gain: $G_p = 39dB$ Typ.
($P_{OUT} = 20.2dBm$, $f = 1.9GHz$)

<Antenna switch receiver block/ low noise down conversion mixer>

- Low current consumption: $I_{DD} = 5.5mA$ Typ.
(When no signal)
- High conversion gain: $G_c = 20.5dB$ Typ.
($f = 1.9GHz$)
- Low distortion: Input $IP_3 = -13dBm$ Typ. ($f = 1.9GHz$)
- High image suppression ratio: $IMR = 40dBc$ Typ.
($f = 1.9GHz$)
- High 1/2 IF suppression ratio: $1/2IFR = 44dBc$ Typ.
($f = 1.9GHz$)

Applications

Japan digital cordless telephones (PHS)

Structure

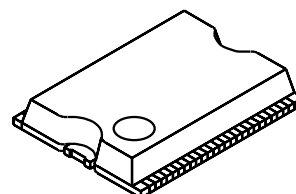
GaAs J-FET MMIC

Note on Handling

GaAs MMICs are ESD sensitive devices. Special handling precautions are required.

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26 pin HSOF (Plastic)



Absolute Maximum Ratings

<Power amplifier block>

• Supply voltage	V_{DD}	6	V
• Voltage between gate and source	V_{GSO}	1.5	V
• Drain current	I_{DD}	550	mA
• Allowable power dissipation	P_D	3	W

<Switch block>

Control voltage	V_{CTL}	6	V
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<Front-end block>

• Supply voltage	V_{DD}	6	V
• Input power	P_{RF}	+10	dBm

<Common to each block>

• Channel temperature	T_{ch}	150	°C
• Operating temperature	T_{opr}	-35 to +85	°C
• Storage temperature	T_{stg}	-65 to +150	°C

Recommended Operating Conditions

<Common to each block>

• Supply voltage	V_{DD}	2.7 to 3.3	V
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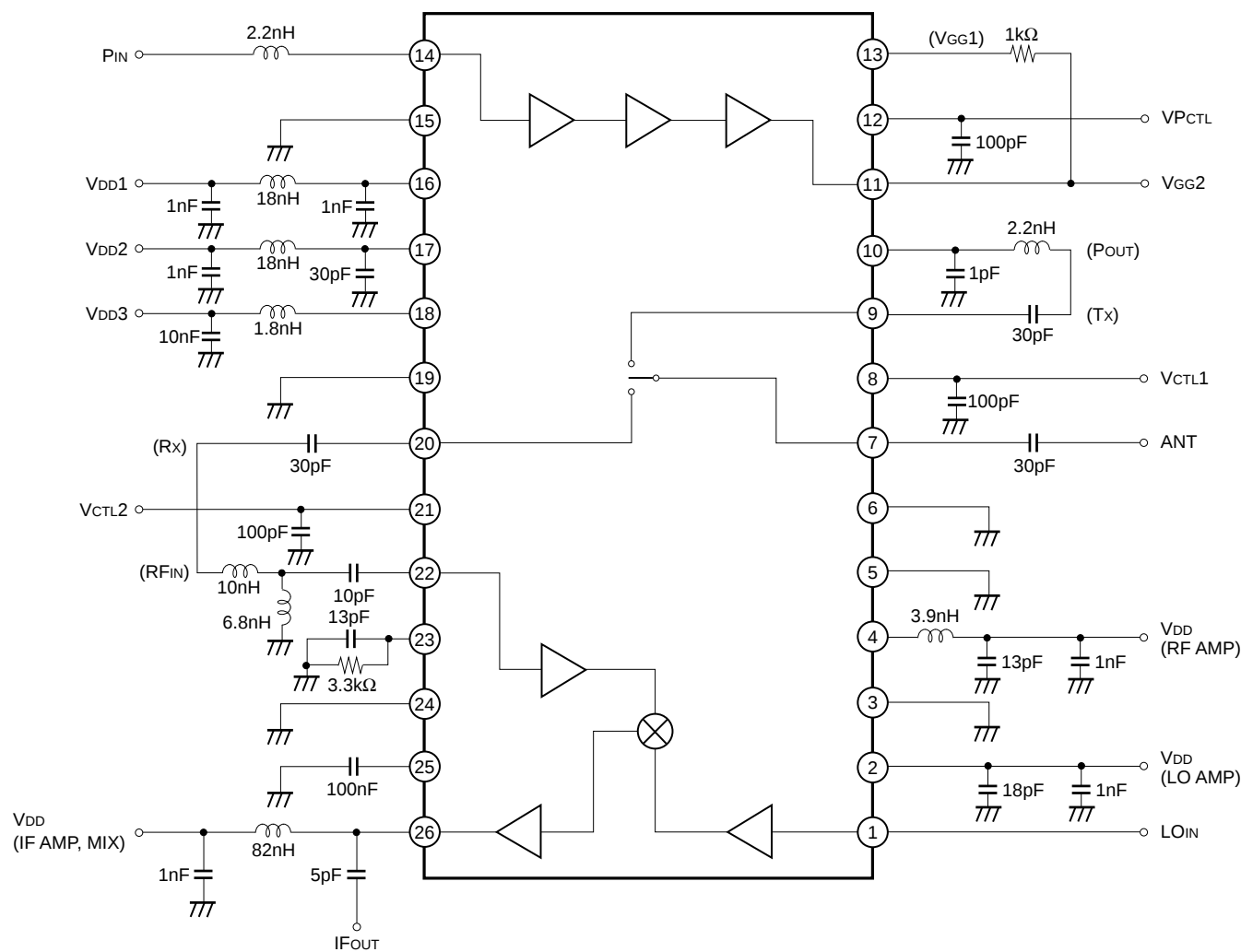
<Power amplifier block>

• Gain control voltage	V_{PCTL}	to $V_{DD} - 1.0$	V
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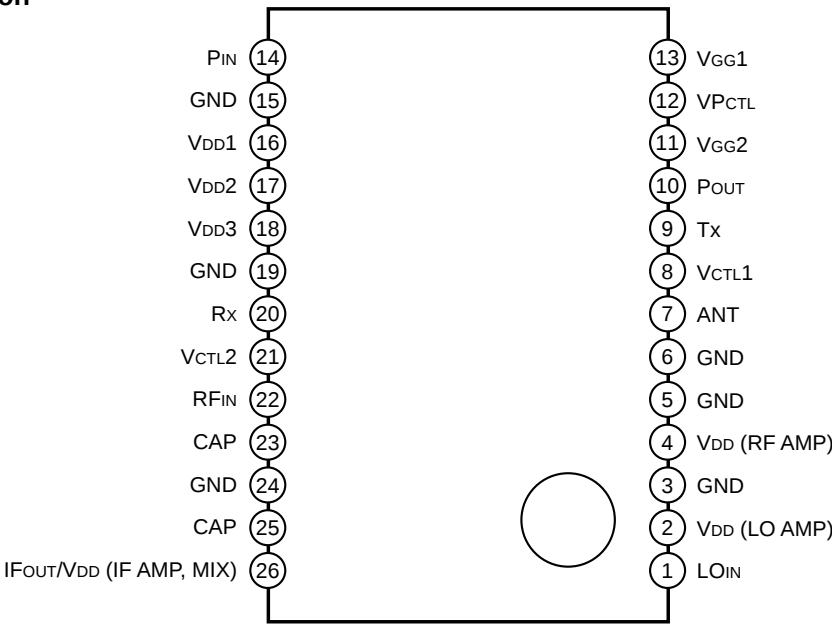
<Switch block>

• Control voltage (H)	$V_{CTL} (H)$	2.9 to 3.3	V
• Control voltage (L)	$V_{CTL} (L)$	0 to 0.2	V

Block Diagram and External Circuit



Pin Configuration



26 pin - HSOF (Plastic)

Electrical Characteristics

1. Control Pin Logic for Antenna Switch

Conditions of control pins	ANT – Tx	ANT – Rx
$V_{CTL1} = 3V, V_{CTL2} = 0V$	ON	OFF
$V_{CTL1} = 0V, V_{CTL2} = 3V$	OFF	ON

2. Power Amplifier Block + Antenna Switch Transmitter Block

These specifications are those when the Sony's recommended evaluation board, shown on page 6, is used.

Unless otherwise specified: $V_{DD} = 3V, V_{PCTL} = 2V, V_{CTL1} = 3V, V_{CTL2} = 0V,$

$I_{DD} = 150mA, P_{OUT} = 20.2dBm, f = 1.9GHz, T_a = 25^{\circ}C$

Item	Symbol	Measurement conditions	Min.	Typ.	Max.	Unit
Current consumption	I_{DD}			150		mA
Gate voltage adjustment value	V_{GG}		0.04	0.25	0.60	V
Output power	P_{OUT}	Measured with the ANT pin	20.2			dBm
Power gain	G_P		36	39		dB
Adjacent channel leak power ratio ($600 \pm 100kHz$)	ACPR600kHz	Measured with the ANT pin		−63	−55	dBc
Adjacent channel leak power ratio ($900 \pm 100kHz$)	ACPR900kHz	Measured with the ANT pin		−70	−60	dBc
Occupied bandwidth	OBW	Measured with the ANT pin		250	275	kHz
2nd-order harmonic level	—	Measured with the ANT pin			−25	dBc
3rd-order harmonic level	—	Measured with the ANT pin			−25	dBc

3. Antenna Switch Receiver Block + Low Noise Down Conversion Mixer Block

These specifications are those when the Sony's recommended evaluation board, shown on page 6, is used.

Unless otherwise specified: $V_{DD} = 3V, V_{CTL1} = 0V, V_{CTL2} = 3V, RF1 = 1.90GHz/-35dBm,$

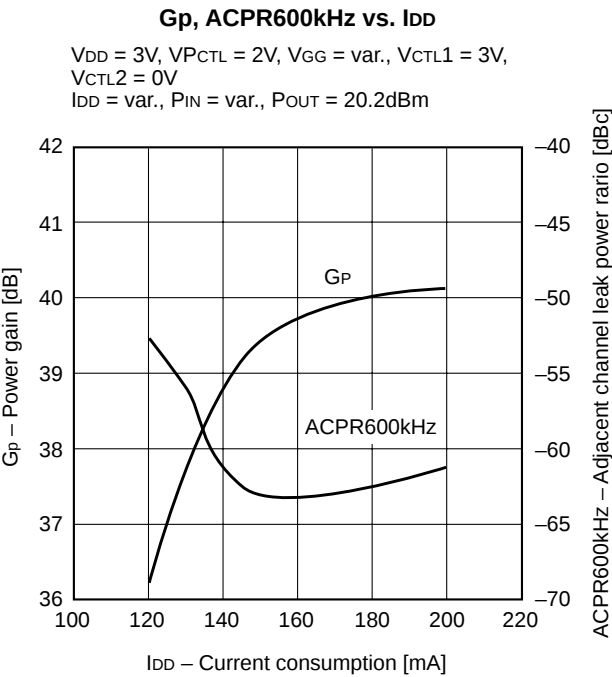
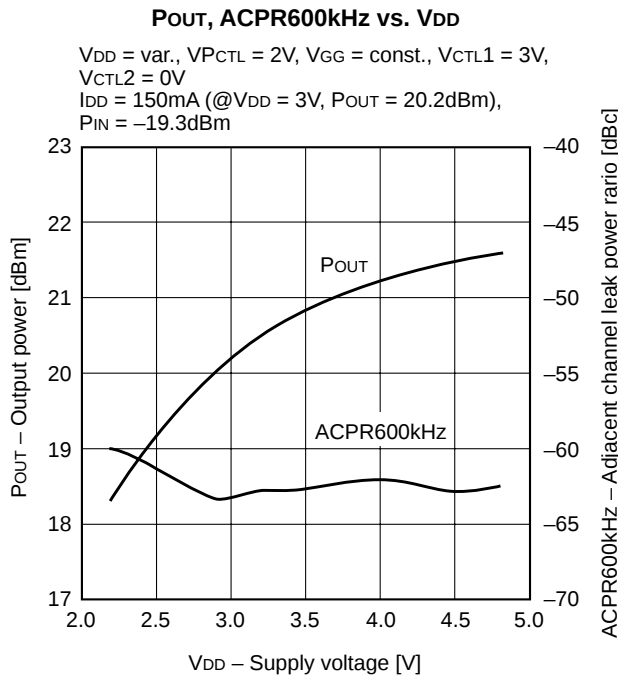
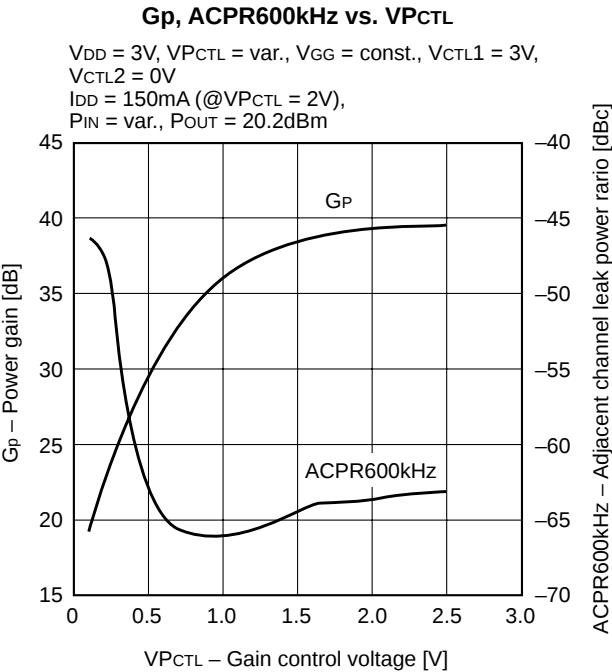
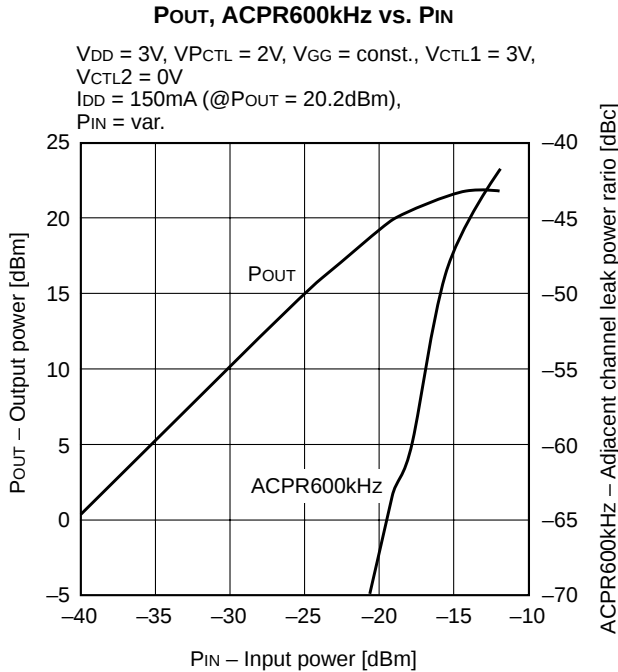
$LO = 1.66GHz/-15dBm, T_a = 25^{\circ}C$

Item	Symbol	Measurement conditions	Min.	Typ.	Max.	Unit
Current consumption	I_{DD}	When no signal		5.5	7.5	mA
Conversion gain	G_C	When a small signal	17	20.5		dB
Noise figure	NF	When a small signal		4.2	5.5	dB
Input IP3	IIP3	*1	−17.5	−13		dBm
Image suppression ratio	IMR	$RF2 = 1.42GHz/-35dBm$	30	40		dBc
1/2 IF suppression ratio	1/2IFR	$RF2 = 1.78GHz/-35dBm$	39	44		dBc
$2 \times LO-IF$ suppression ratio	—	$RF2 = 3.08GHz/-35dBm$	39	47		dBc
$2 \times LO+IF$ suppression ratio	—	$RF2 = 3.56GHz/-35dBm$	24	62		dBc
LO to ANT leak	P_{LK}			−42	−37	dBm

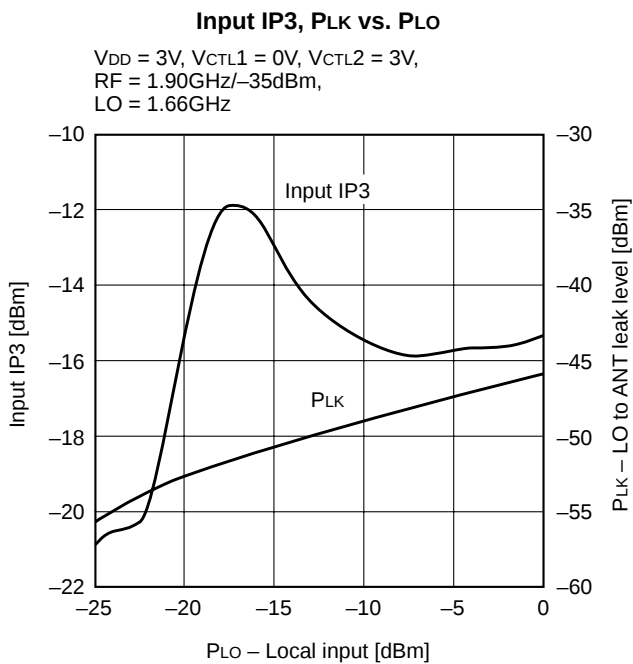
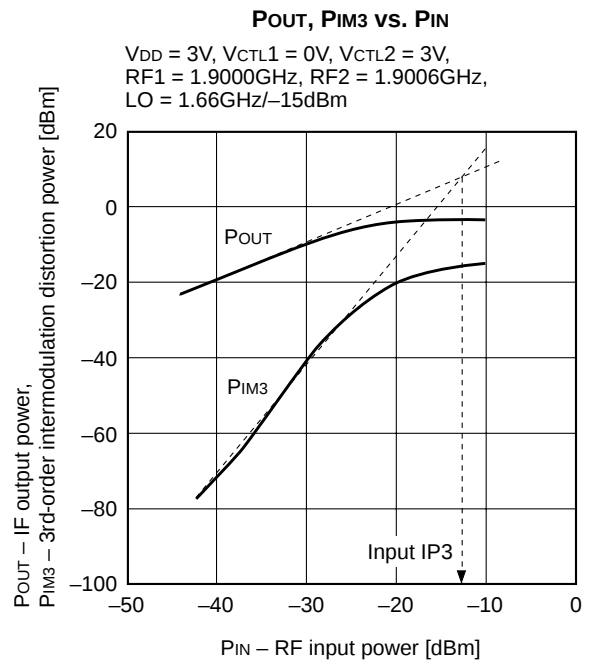
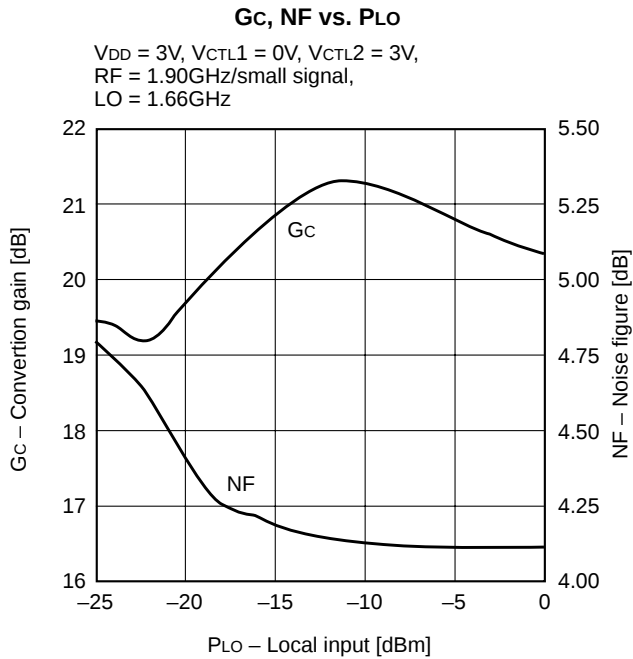
*1 Conversion from IM3 suppression ratio during $FR1 = 1.9000GHz/-35dBm$ and $FR2 = 1.9006GHz/-35dBm$ input.

Example of Representative Characteristics

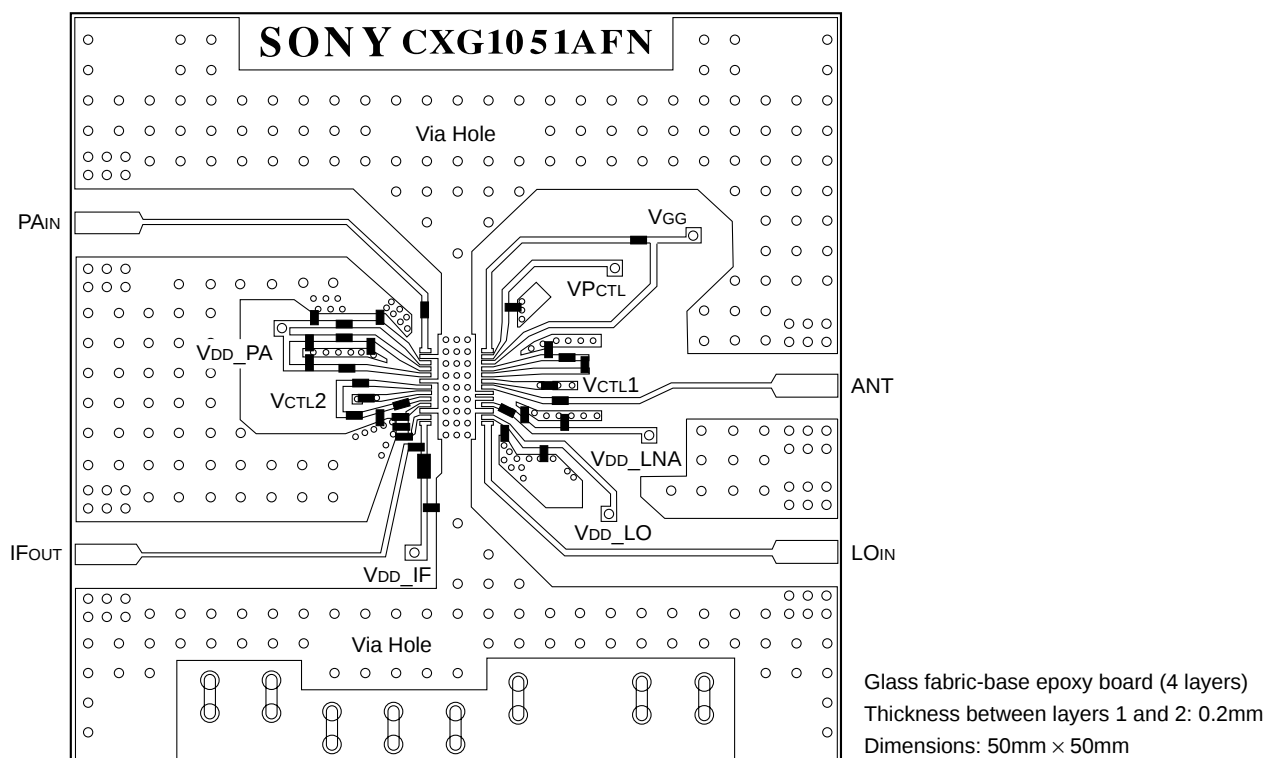
1. Power Amplifier + Antenna Switch Transmitter Block (f = 1.9GHz, Ta = 25°C)



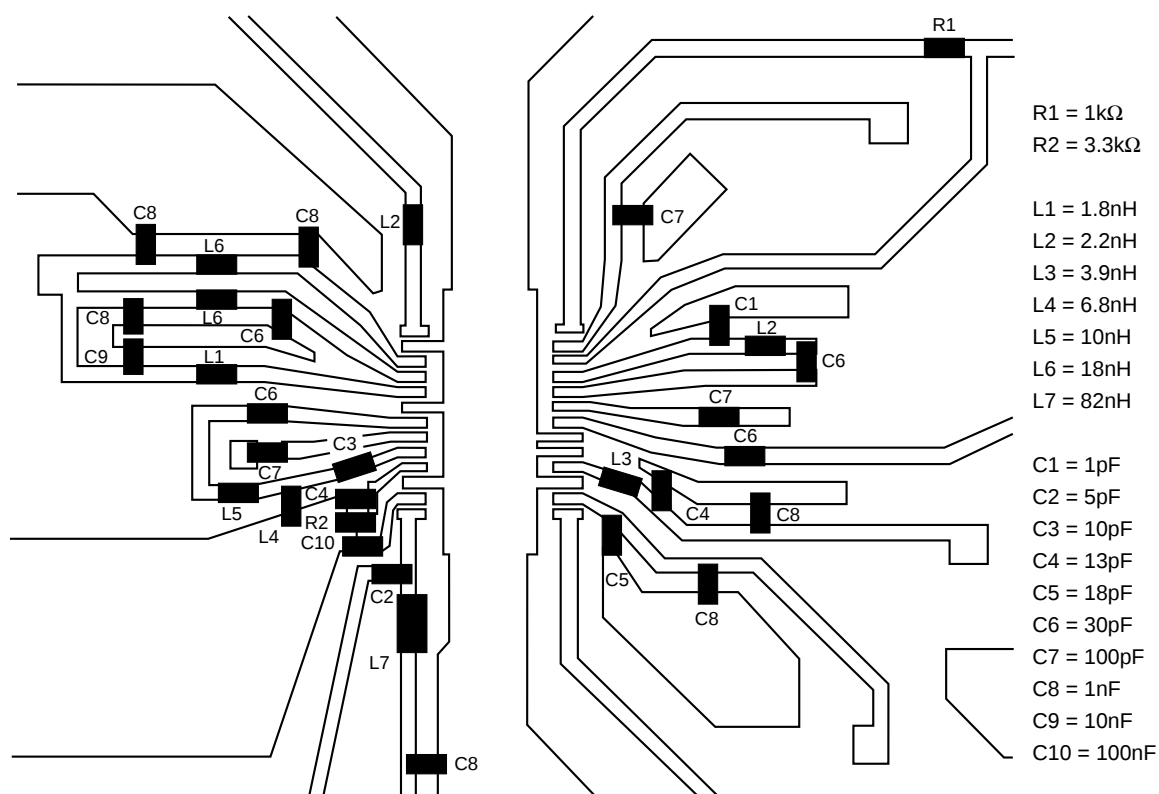
2. Antenna Switch Receiver Block + Low Noise Down Conversion Mixer ($T_a = 25^\circ\text{C}$)



Recommended Evaluation Board



Enlarged Diagram of External Circuit Block



Unit: mm

[illegible]

NOTE: Dimension "+" does not include mold protrusion.

PACKAGE MATERIAL	EPOXY RESIN
LEAD TREATMENT	SOLDER PLATING
LEAD MATERIAL	COPPER ALLOY
PACKAGE MASS	0.06g

Technical drawing of a rectangular metal component, likely a heat exchanger or manifold, showing three views: front, side, and detail B.

Front View (Top Left): Shows a rectangular body with a central circular feature. Dimensions include overall width 5.6 ± 0.05 , overall height 4.4 ± 0.1 , and a central circular feature with diameter 0.07 . A section line A-A is indicated.

Side View (Top Right): Shows the profile of the component. Dimensions include overall width 0.9 ± 0.1 , overall height 0.45 ± 0.15 , and a central circular feature with diameter 0.08 . A section line S-S is indicated.

Detail B (Bottom Left): A close-up view of a corner or joint, showing a circular feature with diameter 0.07 and a section line B-B.

Detail B (Bottom Right): A close-up view of a corner or joint, showing a circular feature with diameter 0.07 and a section line B-B. The drawing includes dimensions for the corner radius and the thickness of the material.

NOTE: Dimension "*" does not include mold protrusion.

PACKAGE STRUCTURE	
PACKAGE MATERIAL	EPOXY RESIN
LEAD TREATMENT	SOLDER PLATING
LEAD MATERIAL	COPPER ALLOY
PACKAGE MASS	0.06g

ITEM	SPEC.
LEAD MATERIAL	COPPER ALLOY
SOLDER COMPOSITION	Sn-Bi Bi:1-4wt%
PLATING THICKNESS	5-18μm